

SKiiP 26AC066V1



MiniSKiiP® 2

3-phase bridge Inverter

SKiiP 26AC066V1

Target Data

Features

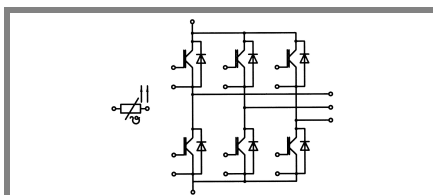
- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connection
- UL recognised file no. E63532

Typical Applications

- Inverter up to 12,5 kVA
- Typical motor power 5,5 kW

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter			
V_{CES}		600	V
I_C	$T_s = 25\text{ (70) °C}$		A
I_{CRM}	$T_s = 25\text{ (70) °C}$, $t_p \leq 1\text{ ms}$		A
V_{GES}		± 20	V
T_j		- 40 ... + 150	°C
Diode - Inverter			
I_F	$T_s = 25\text{ (70) °C}$		A
I_{FRM}	$T_s = 25\text{ (70) °C}$, $t_p \leq 1\text{ ms}$		A
T_j		- 40 ... + 150	°C
I_{tRMS}	per power terminal (20 A / spring)	100	A
T_{stg}	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter					
V_{CEsat}	$I_C = 50\text{ A}$, $T_j = 25\text{ (125) °C}$		2 (2,2)	2,5 (2,7)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 1\text{ mA}$	3	4	5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1,2 (1,1)	1,3 (1,2)	V
r_T	$T_j = 25\text{ (125) °C}$		16 (22)	24 (30)	mΩ
C_{ies}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		2,7		nF
C_{oes}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		0,8		nF
C_{res}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		0,6		nF
$R_{th(j-s)}$	per IGBT		0,75		K/W
$t_{d(on)}$	under following conditions		30		ns
t_r	$V_{CC} = 300\text{ V}$, $V_{GE} = \pm 15\text{ V}$		25		ns
$t_{d(off)}$	$I_C = 50\text{ A}$, $T_j = 125\text{ °C}$		205		ns
t_f	$R_{Gon} = R_{Goff} = 12\text{ Ω}$		25		ns
E_{on}	inductive load		1,3		mJ
E_{off}			0,9		mJ
Diode - Inverter					
$V_F = V_{EC}$	$I_F = 50\text{ A}$, $T_j = 25\text{ (125) °C}$		1,9 (1,9)	2,3 (2,4)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,1 (1)	V
r_T	$T_j = 25\text{ (125) °C}$		18 (20)	24 (28)	mΩ
$R_{th(j-s)}$	per diode		1,5		K/W
I_{RRM}	under following conditions		57		A
Q_{rr}	$I_F = 50\text{ A}$, $V_R = 300\text{ V}$		4,6		μC
E_{rr}	$V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$		0,9		mJ
	$di_F/dt = 2400\text{ A/μs}$				
Temperature Sensor					
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
Mechanical Data					
m			65		g
M_s	Mounting torque	2		2,5	Nm



AC

